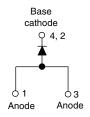


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High Performance Schottky Rectifier, 3.0 A





D-PAK	(TO-252AA)	

PRODUCT SUMMARY						
Package	D-PAK (TO-252AA)					
I _{F(AV)}	3.0 A					
V _R	20 V, 30 V, 40 V					
V _F at I _F	0.49 V					
I _{RM}	20 mA at 125 °C					
T _J max.	150 °C					
Diode variation	Single die					
Eas	8 mJ					

FEATURES

- Low forward voltage drop
- Guard ring for enhanced ruggedness and long term reliability



FREE

- Popular D-PAK outline
- · Small foot print, surface mountable
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

The VS-MBRD320-M3, VS-MBRD330-M3, VS-MBRD340-M3 surface mount Schottky rectifier has been designed for applications requiring low forward drop and small foot prints on PC boards. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL	CHARACTERISTICS	VALUES	UNITS				
I _{F(AV)}	Rectangular waveform	3.0	A				
V _{RRM}		20 to 40	V				
I _{FSM}	t _p = 5 μs sine	490	Α				
V _F	3 A _{pk} , T _J = 125 °C	0.49	V				
TJ		-40 to +150	°C				

VOLTAGE RATINGS							
PARAMETER SYMBOL VS-MBRD320-M3 VS-MBRD330-M3 VS-MBRD340-M3 UNITS							
Maximum DC reverse voltage	V_{R}	20	30	40	V		
Maximum working peak reverse voltage	V_{RWM}	20	30	40	V		

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST CONDI	TIONS	VALUES	UNITS			
Maximum average forward current	I _{F(AV)}	50 % duty cycle at T _L = 133 °C, re	3.0					
Maximum peak one cycle	I _{FSM}	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated	490	А			
non-repetitive surge current		10 ms sine or 6 ms rect. pulse	V _{RRM} applied	75				
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 1 A, L = 16 mH		8.0	mJ			
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in Frequency limited by T _J maximum	•	1.0	А			



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ELECTRICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CO	ONDITIONS	TYP.	MAX.	UNITS	
		3 A	T _{.1} = 25 °C	0.48	0.6	V	
Maximum forward voltage drop	V _{FM} ⁽¹⁾	6 A	1]=25 0	0.58	0.7		
See fig. 1	VFM ('')	3 A	T 105 °C	0.41	0.49		
		6 A	T _J = 125 °C	0.55	0.625		
Maximum reverse leakage current	I _{RM} ⁽¹⁾	T _J = 25 °C	V _B = Rated V _B	0.02	0.2	mA	
See fig. 2	IRM ***	T _J = 125 °C	VR = nateu VR	10.7	20	IIIA	
Typical junction capacitance	C _T	V _R = 5 V _{DC} (test signal ran	189	-	pF		
Typical series inductance	L _S	Measured lead to lead 5 n	5.0	-	nΗ		
Maximum voltage rate of change	dV/dt	Rated V _R		-	10 000	V/µs	

Note

 $^{^{(1)}\,}$ Pulse width < 300 µs, duty cycle < 2 %

PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction temperature range	T _J ⁽¹⁾		-40 to +150	20
Maximum storage temperature range	T _{Stg}		-40 to +175	°C
Maximum thermal resistance, junction to case	R _{thJC}	DC operation See fig. 4	6.0	°C AM
Maximum thermal resistance, junction to ambient	R _{thJA}		80	°C/W
Annyayimata waight			0.3	g
Approximate weight			0.01	OZ.
			MBRI	D320
Marking device		Case style D-PAK (similar to TO-252AA)	MBRD330	
			MBRI	D340

Note

(1)
$$\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$$
 thermal runaway condition for a diode on its own heatsink

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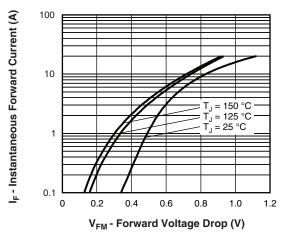


Fig. 1 - Maximum Forward Voltage Drop Characteristics

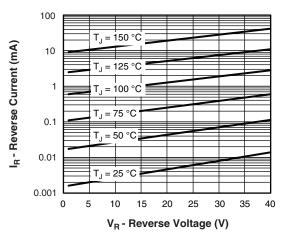


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

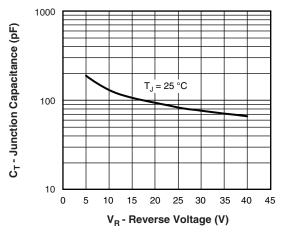


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

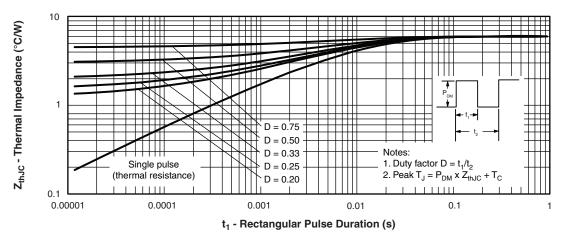


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics



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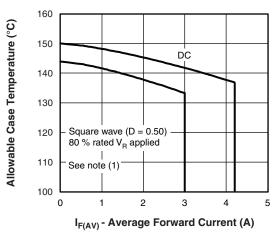


Fig. 5 - Maximum Allowable Case Temperature vs.
Average Forward Current

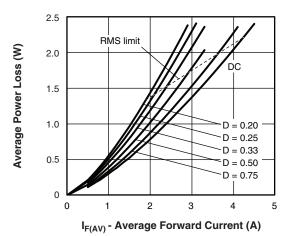


Fig. 6 - Forward Power Loss Characteristics

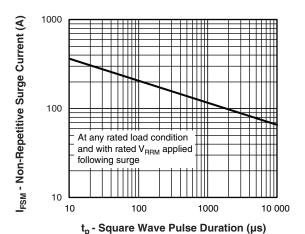


Fig. 7 - Maximum Non-Repetitive Surge Current

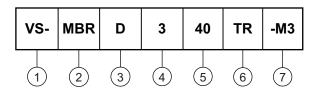
Note

 $^{(1)}$ Formula used: T_C = T_J - (Pd + Pd_{REV}) x R_{th,JC}; Pd = forward power loss = I_{F(AV)} x V_{FM} at (I_{F(AV)}/D) (see fig. 6); Pd_{REV} = inverse power loss = V_{R1} x I_R (1 - D); I_R at V_{R1} = 80 % rated V_R

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ORDERING INFORMATION TABLE

Device code



Vishay Semiconductors product

Schottky MBR series

D = TO-252AA (D-PAK)

Current rating (3 = 3 A)

20 = 20 VVoltage ratings -30 = 30 V40 = 40 V

• None = tube

• TR = tape and reel

• TRL = tape and reel (left oriented)

• TRR = tape and reel (right oriented)

7 Environmental digit:

-M3 = halogen-free, RoHS-compliant and terminations lead (Pb)-free

ORDERING INFORMATION (Example)								
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION					
VS-MBRD320-M3	75	3000	Antistatic plastic tube					
VS-MBRD320TR-M3	2000	2000	13" diameter reel					
VS-MBRD320TRL-M3	3000	3000	13" diameter reel					
VS-MBRD320TRR-M3	3000	3000	13" diameter reel					
VS-MBRD330-M3	75	3000	Antistatic plastic tube					
VS-MBRD330TR-M3	2000	2000	13" diameter reel					
VS-MBRD330TRL-M3	3000	3000	13" diameter reel					
VS-MBRD330TRR-M3	3000	3000	13" diameter reel					
VS-MBRD340-M3	75	3000	Antistatic plastic tube					
VS-MBRD340TR-M3	2000	2000	13" diameter reel					
VS-MBRD340TRL-M3	3000	3000	13" diameter reel					
VS-MBRD340TRR-M3	3000	3000	13" diameter reel					

LINKS TO RELATED DOCUMENTS					
Dimensions <u>www.vishay.com/doc?95627</u>					
Part marking information	www.vishay.com/doc?95176				
Packaging information	www.vishay.com/doc?95033				



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D-PAK (TO-252AA) "M"

DIMENSIONS in millimeters and inches



SYMBOL	MILLIN	IETERS	INCHES		NOTES
STINIBUL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	2.18	2.39	0.086	0.094	
A1	-	0.13	-	0.005	
b	0.64	0.89	0.025	0.035	
b2	0.76	1.14	0.030	0.045	
b3	4.95	5.46	0.195	0.215	3
С	0.46	0.61	0.018	0.024	
c2	0.46	0.89	0.018	0.035	
D	5.97	6.22	0.235	0.245	5
D1	5.21	-	0.205	1	3
Е	6.35	6.73	0.250	0.265	5
E1	4.32	-	0.170	-	3

SYMBOL	MILLIN	IETERS	INCHES		NOTES
STINIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
е	2.29	BSC	0.090	BSC	
Н	9.40	10.41	0.370	0.410	
L	1.40	1.78	0.055	0.070	
L1	2.74 BSC		0.108 REF.		
L2	0.51	BSC	0.020 BSC		
L3	0.89	1.27	0.035	0.050	3
L4	-	1.02	-	0.040	
L5	1.14	1.52	0.045	0.060	2
Ø	0°	10°	0°	10°	
Ø1	0°	15°	0°	15°	
Ø2	25°	35°	25°	35°	

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension uncontrolled in L5
- (3) Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad
- (4) Section C C dimension apply to the flat section of the lead between 0.13 and 0.25 mm (0.005 and 0.10") from the lead tip
- (5) Dimension D, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (6) Dimension b1 and c1 applied to base metal only
- (7) Datum A and B to be determined at datum plane H
- (8) Outline conforms to JEDEC® outline TO-252AA



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